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**37 CFR 1.7(c) FILING RECEIPT AND  
TRANSMITTAL LETTER WITH  
AUTHORIZATION TO CHARGE DEPOSIT ACCOUNT**

Neifeld Docket No.: OSEMDB15UPCTUS  
US/PCT Application/Patent No.: 10/579,537  
Priority Data: US04/38582 filed 11/17/2004  
Inventor: BRADDOCK  
Title: Nitride Metal Oxide Semiconductor Integrated Transistor Devices

Client Ref.:  
US/PCT File/Issue Date: 5/16/2006  
USPTO Confirmation No.: unknown

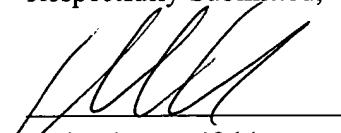
**THE FOLLOWING HAS BEEN RECEIVED IN THE U.S. PATENT OFFICE ON  
THE DATE STAMPED HEREON:**

37 CFR 1.7(c) Filing Receipt and Transmittal Letter with Authorization to Charge Deposit Account (1 page in duplicate)  
37 CFR 1.115 Preliminary Amendment (5 pages).

The Commissioner is hereby authorized to charge any fees which may be required, or credit any overpayment, to Deposit Account Number 50-2106. A duplicate copy of this sheet is enclosed.

6/16/06  
DATE

Respectfully Submitted,



Richard A. Neifeld  
Registration No. 35,299  
Attorney of Record

Fees:	PcLaw Matter	Lawyer	Amount	Explanation	Date Entered	Initials
Fees:						
Disbursements:	PcLaw Matter	G/L Account	Amount	Explanation	Date Entered	Initials
			5010			



NEIFELD DOCKET NO: OSEMDB15UPCTUS

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF: BRADDOCK

APPLICATION NO: UNKNOWN

CONFIRMATION NO:

NATIONAL STAGE OF PCT/US04/38582 filed 11/17/2004

FILED: Herewith

EXAMINER:

GROUP ART UNIT:

TITLE: Nitride Metal Oxide Semiconductor Integrated Transistor Devices

ASSISTANT COMMISSIONER FOR PATENTS

ALEXANDRIA, VA 22313

37 CFR 1.115 PRELIMINARY AMENDMENT

Sir:

Please enter this amendment prior to examining this application.